NSN 5961-00-814-2677

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-814-2677 **Inclosure Material:** Metal **Overall Length:** 1.204 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-64 **Mounting Method:** Threaded stud **Features Provided:** Burn in and hermetically sealed case **Overall Width Across Flats:** 0.430 inches **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak and 1.85 forward voltage, peak and 2.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes forward current, total rms preset and 4.70 amperes forward current, total rms megahertz **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Internal junction configuration arrangement npnp **Thread Series Designator: Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig:

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